

BTA25H-600CW3G, BTA25H-800CW3G



Expertise Applied | Answers Delivered

Triacs Silicon Bidirectional Thyristors

Designed for high performance full-wave ac control applications where high noise immunity and high commutating di/dt are required.

Features

- Blocking Voltage to 800 Volts
- On-State Current Rating of 25 Amperes RMS at 95°C
- Uniform Gate Trigger Currents in Three Quadrants
- High Immunity to dV/dt – 500 V/μs minimum at 150°C
- Minimizes Snubber Networks for Protection
- Industry Standard TO-220AB Package – Internally Isolated
- High Commutating di/dt – 4.0 A/ms minimum at 150°C
- Internally Isolated (2500 V_{RMS})
- These are Pb-Free Devices

MAXIMUM RATINGS (T_J = 25°C unless otherwise noted)

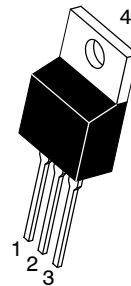
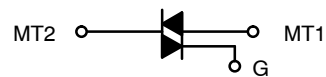
Rating	Symbol	Value	Unit
Peak Repetitive Off-State Voltage (Note 1) (T _J = -40 to 150°C, Sine Wave, 50 to 60 Hz, Gate Open) BTA25H-600CW3G BTA25H-800CW3G	V _{DRM} , V _{RRM}	600 800	V
On-State RMS Current (Full Cycle Sine Wave, 60 Hz, T _C = 95°C)	I _{T(RMS)}	25	A
Peak Non-Repetitive Surge Current (One Full Cycle Sine Wave, 60 Hz, T _C = 25°C)	I _{TSM}	250	A
Circuit Fusing Consideration (t = 8.3 ms)	I ² t	260	A ² sec
Non-Repetitive Surge Peak Off-State Voltage (T _J = 25°C, t = 8.3 ms)	V _{DSM} / V _{RSM}	V _{DRM} /V _{RRM} +100	V
Peak Gate Current (T _J = 150°C, t ≤ 20 μs)	I _{GM}	4.0	A
Average Gate Power (T _J = 150°C)	P _{G(AV)}	0.5	W
Operating Junction Temperature Range	T _J	-40 to +150	°C
Storage Temperature Range	T _{stg}	-40 to +150	°C
RMS Isolation Voltage (t = 300 ms, R.H. ≤ 30%, T _A = 25°C)	V _{iso}	2500	V

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

1. V_{DRM} and V_{RRM} for all types can be applied on a continuous basis. Blocking voltages shall not be tested with a constant current source such that the voltage ratings of the devices are exceeded.

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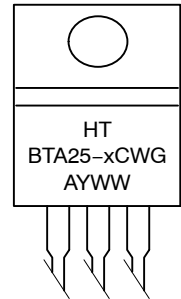
TRIACS 25 AMPERES RMS 600 thru 800 VOLTS



TO-220AB
CASE 221A
STYLE 12

- x = 6 or 8
- A = Assembly Location
- Y = Year
- WW = Work Week
- G = Pb-Free Package

MARKING DIAGRAM



PIN ASSIGNMENT

Pin	Assignment
1	Main Terminal 1
2	Main Terminal 2
3	Gate
4	No Connection

ORDERING INFORMATION

Device	Package	Shipping
BTA25H-600CW3G	TO-220AB (Pb-Free)	50 Units / Rail
BTA25H-800CW3G	TO-220AB (Pb-Free)	50 Units / Rail

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THERMAL CHARACTERISTICS

Characteristic	Symbol	Value	Unit
Thermal Resistance, Junction-to-Case (AC)	$R_{\theta JC}$	1.8	$^{\circ}\text{C}/\text{W}$
Junction-to-Ambient	$R_{\theta JA}$	60	
Maximum Lead Temperature for Soldering Purposes 1/8" from Case for 10 seconds	T_L	260	$^{\circ}\text{C}$

ELECTRICAL CHARACTERISTICS ($T_J = 25^{\circ}\text{C}$ unless otherwise noted; Electricals apply in both directions)

Characteristic	Symbol	Min	Typ	Max	Unit
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OFF CHARACTERISTICS

Peak Repetitive Blocking Current ($V_D = \text{Rated } V_{DRM}, V_{RRM}; \text{ Gate Open}$)	I_{DRM}, I_{RRM}	-	-	0.005	mA
		-	-	15	

ON CHARACTERISTICS

Peak On-State Voltage (Note 2) ($I_{TM} = \pm 35 \text{ A Peak}$)	V_{TM}	-	-	1.55	V
Gate Trigger Current (Continuous dc) ($V_D = 12 \text{ V}, R_L = 30 \Omega$)	I_{GT}	-	-	35	mA
MT2(+), G(+)		-	-	35	
MT2(+), G(-)		-	-	35	
MT2(-), G(-)		-	-	35	
Holding Current ($V_D = 12 \text{ V}, \text{ Gate Open}, \text{ Initiating Current} = \pm 100 \text{ mA}$)	I_H	-	-	50	mA
Latching Current ($V_D = 12 \text{ V}, I_G = 42 \text{ mA}$)	I_L	-	-	75	mA
MT2(+), G(+)		-	-	75	
MT2(+), G(-)		-	-	75	
MT2(-), G(-)		-	-	75	
Gate Trigger Voltage ($V_D = 12 \text{ V}, R_L = 30 \Omega$)	V_{GT}	-	-	1.3	V
MT2(+), G(+)		-	-	1.3	
MT2(+), G(-)		-	-	1.3	
MT2(-), G(-)		-	-	1.3	
Gate Non-Trigger Voltage ($T_J = 150^{\circ}\text{C}$)	V_{GD}	0.15	-	-	V
MT2(+), G(+)		0.15	-	-	
MT2(+), G(-)		0.15	-	-	
MT2(-), G(-)		0.15	-	-	

DYNAMIC CHARACTERISTICS

Rate of Change of Commutating Current, See Figure 10. (Gate Open, $T_J = 150^{\circ}\text{C}$, No Snubber)	$(di/dt)_c$	4.0	-	-	A/ms
Critical Rate of Rise of On-State Current ($T_J = 150^{\circ}\text{C}, f = 120 \text{ Hz}, I_G = 2 \times I_{GT}, tr \leq 100 \text{ ns}$)	di/dt	-	-	50	A/ μs
Critical Rate of Rise of Off-State Voltage ($V_D = 0.66 \times V_{DRM}$, Exponential Waveform, Gate Open, $T_J = 150^{\circ}\text{C}$)	dV/dt	500	-	-	V/ μs

2. Indicates Pulse Test: Pulse Width $\leq 2.0 \text{ ms}$, Duty Cycle $\leq 2\%$.

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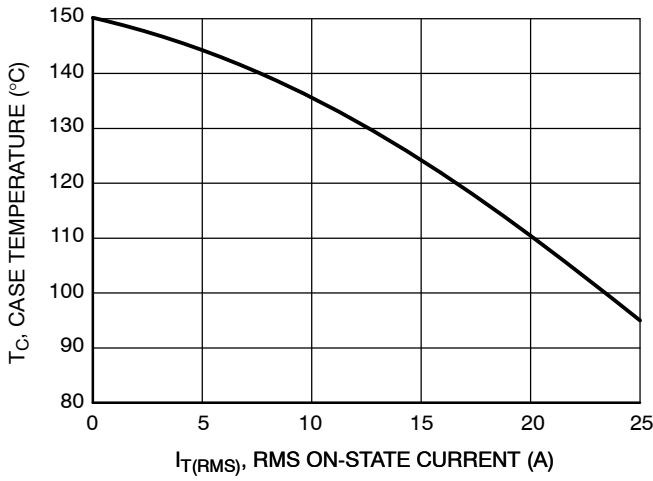


Figure 1. RMS Current Derating

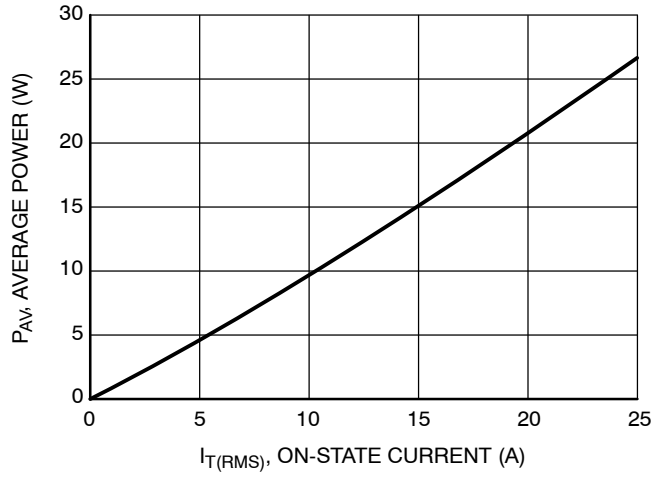


Figure 2. On-State Power Dissipation

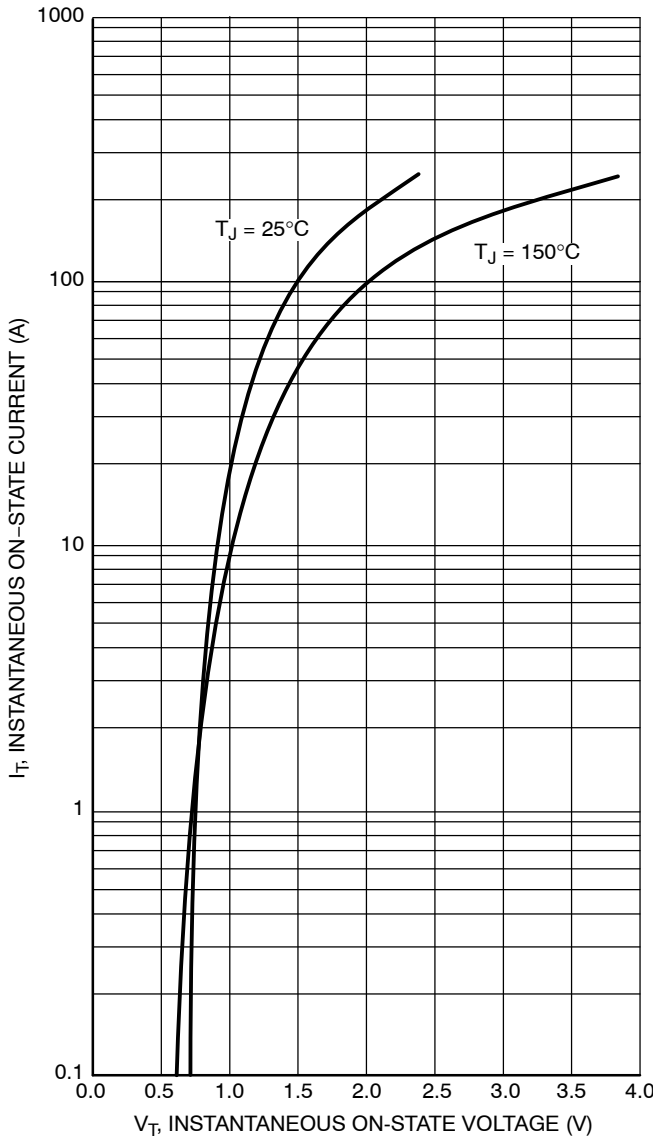


Figure 3. On-State Characteristics

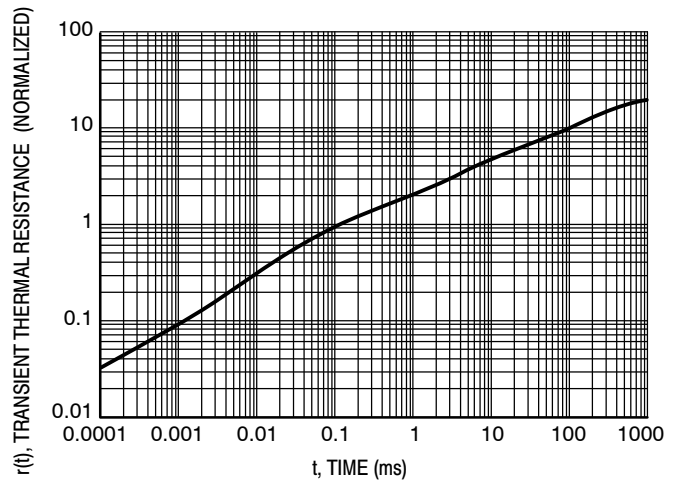


Figure 4. Thermal Response

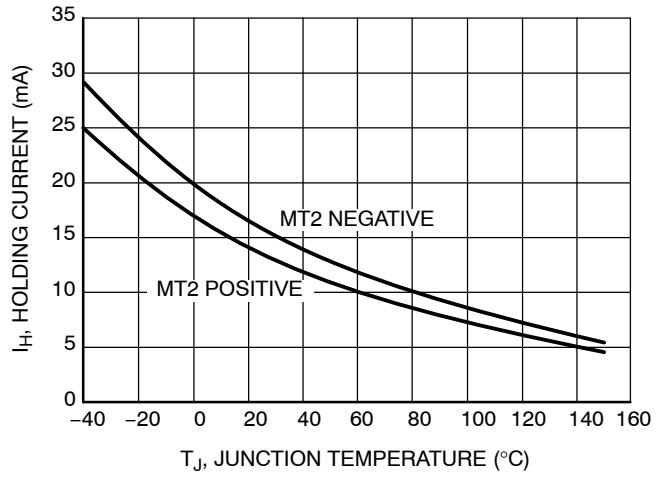


Figure 5. Hold Current Variation

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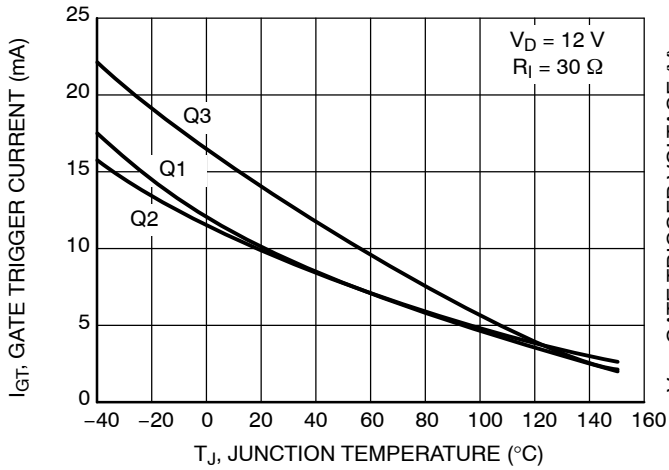


Figure 6. Gate Trigger Current Variation

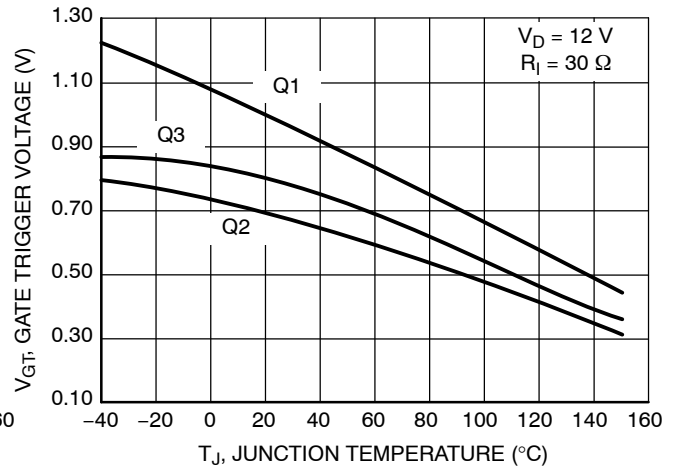


Figure 7. Gate Trigger Voltage Variation

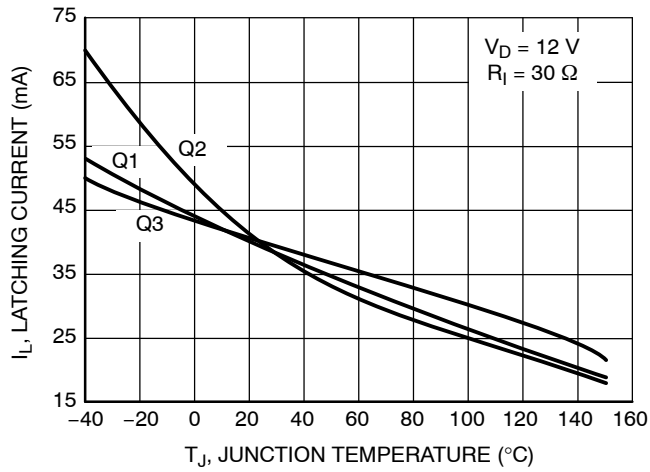
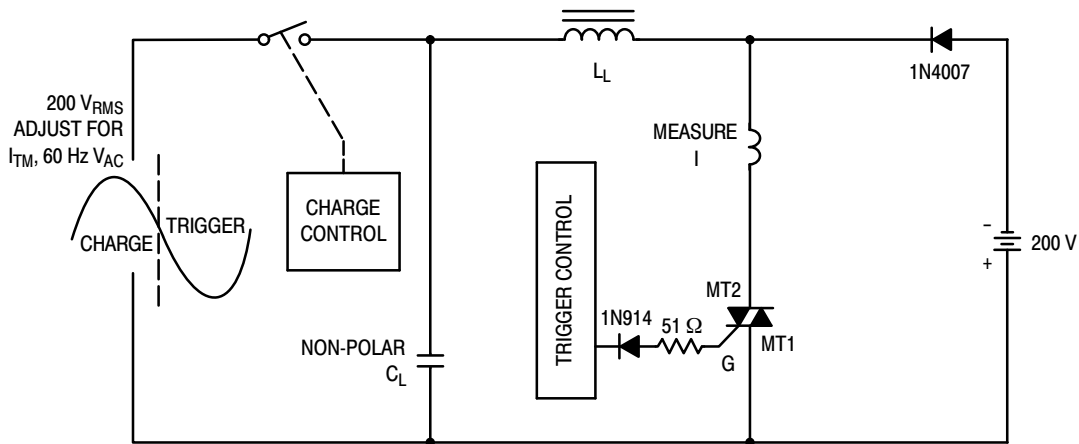


Figure 8. Latching Current Voltage



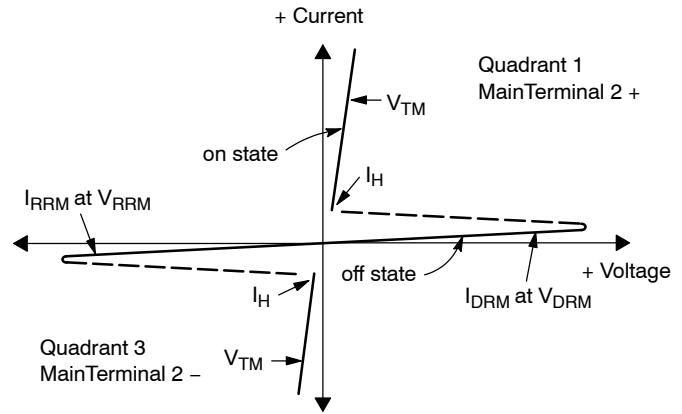
Note: Component values are for verification of rated $(di/dt)_c$. See AN1048 for additional information.

Figure 9. Simplified Test Circuit to Measure the Critical Rate of Rise of Commutating Current $(di/dt)_c$

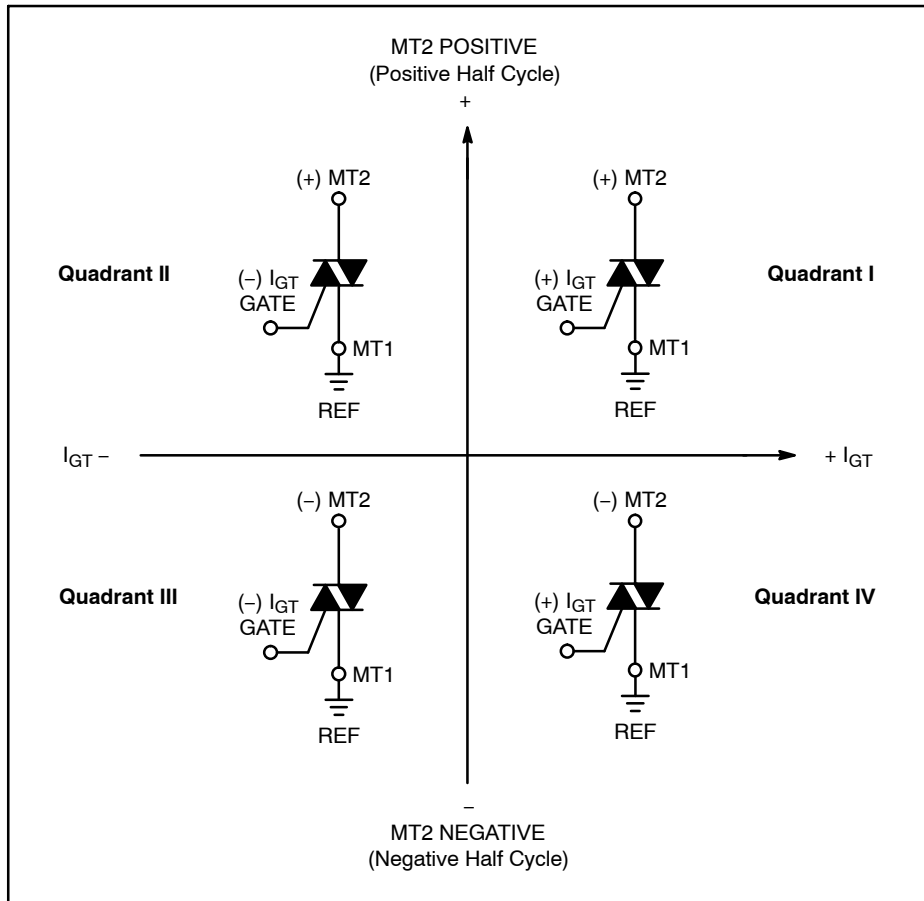
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Voltage Current Characteristic of Triacs (Bidirectional Device)

Symbol	Parameter
V_{DRM}	Peak Repetitive Forward Off State Voltage
I_{DRM}	Peak Forward Blocking Current
V_{RRM}	Peak Repetitive Reverse Off State Voltage
I_{RRM}	Peak Reverse Blocking Current
V_{TM}	Maximum On State Voltage
I_H	Holding Current



Quadrant Definitions for a Triac



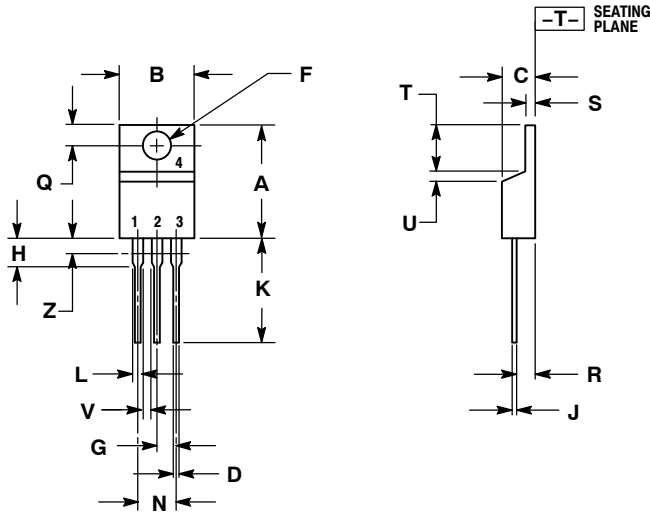
All polarities are referenced to MT1.

With in-phase signals (using standard AC lines) quadrants I and III are used.

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PACKAGE DIMENSIONS

TO-220
CASE 221A-07
ISSUE AA



- NOTES:
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 2. CONTROLLING DIMENSION: INCH.
 3. DIMENSION Z DEFINES A ZONE WHERE ALL BODY AND LEAD IRREGULARITIES ARE ALLOWED.

DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.570	0.620	14.48	15.75
B	0.380	0.405	9.66	10.28
C	0.160	0.190	4.07	4.82
D	0.025	0.035	0.64	0.88
F	0.142	0.147	3.61	3.73
G	0.095	0.105	2.42	2.66
H	0.110	0.155	2.80	3.93
J	0.014	0.022	0.36	0.55
K	0.500	0.562	12.70	14.27
L	0.045	0.060	1.15	1.52
N	0.190	0.210	4.83	5.33
Q	0.100	0.120	2.54	3.04
R	0.080	0.110	2.04	2.79
S	0.045	0.055	1.15	1.39
T	0.235	0.255	5.97	6.47
U	0.000	0.050	0.00	1.27
V	0.045	---	1.15	---
Z	---	0.080	---	2.04

- STYLE 12:
1. MAIN TERMINAL 1
 2. MAIN TERMINAL 2
 3. GATE
 4. NOT CONNECTED

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